查询AD9066供应商

Dual 6-Bit, 60 MSPS Monolithic A/D Converter

AD9066

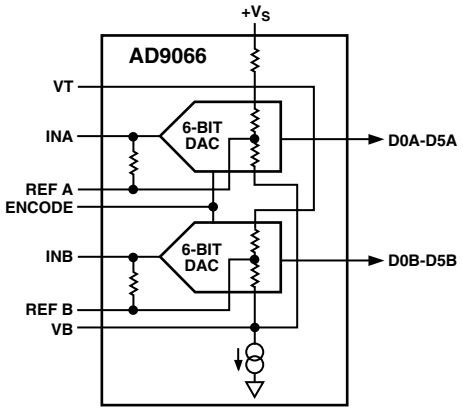
FEATURES

Two Matched ADCs on Single Chip
CMOS-Compatible I/O
Low-Power (400 mW) Dissipation
Single +5 V Supply
On-Chip Voltage Reference
Self-Biased for AC-Coupled Inputs
28-Lead SOIC and SSOP Packages

APPLICATIONS

Direct Broadcast Satellite (DBS) Receivers
QAM Demodulators
Wireless LANs
VSAT Receivers

FUNCTIONAL BLOCK DIAGRAM



PRODUCT DESCRIPTION

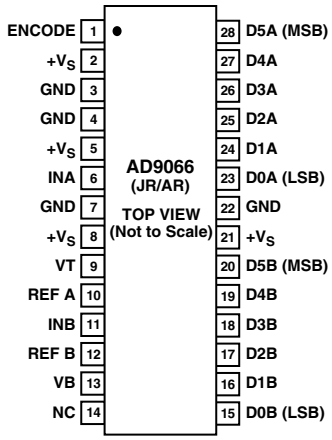
The AD9066 is a dual 6-bit ADC that has been optimized for low-cost in-phase and quadrature (I and Q) demodulators. Primary applications include digital direct broadcast satellite applications where broadband quadrature phase shift keying (QPSK) modulation is used. In these receivers the recovered signal is separated into I and Q vector components and digitized.

To reduce total system cost and power dissipation, the AD9066 provides an internal voltage reference and operates from a single +5 volt power supply. Digital outputs are CMOS compatible and rated to 60 MSPS conversion rates. The digital input (ENCODE) utilizes a CMOS input stage with a TTL compatible (1.4 V) threshold.

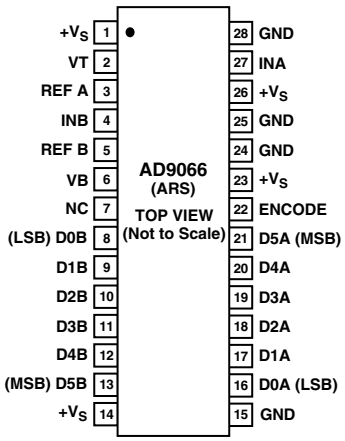
The AD9066 is housed in a 28-lead SOIC and a 28-lead SSOP package and is available in two temperature grades. The AD9066JR is rated for operation over the 0°C to 70°C commercial temperature range. The AD9066AR/ARS is rated for the –40°C to +85°C industrial temperature range.

The internal voltage reference insures that the analog input is biased to midscale with low offset when driven from an ac-coupled source. In dc-coupled applications, the midscale voltage reference can be used to control external biasing amplifiers to minimize offsets due to variations in temperature or supply voltage.

PIN CONFIGURATIONS



NC = NO CONNECT



NC = NO CONNECT

REV. A

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AD9066–SPECIFICATIONS

ELECTRICAL CHARACTERISTICS ($+V_S$ = +5 V, AIN = 15.5 MHz, Encode Rate = 60 MSPS, $T_C = T_A$)

Parameter	Test Level	Temp	AD9066JR Min	AD9066JR Typ	AD9066JR Max	AD9066AR/ARS Min	AD9066AR/ARS Typ	AD9066AR/ARS Max	Unit
ANALOG INPUT									
Full-Scale Input Range	VI	Full	475	500	525	450	500	530	mV
Gain Matching (FS Range)	IV	Full			16			16	mV
DC Input (Midscale)[1]	V	+25°C		$+V_S - 1.1$			$+V_S - 1.1$		V
Input Offset[1]	VI	Full	–1.0		+1.0	–1.0		+1.0	LSBs
Input Capacitance	IV	Full		10	15		10	15	pF
Input Resistance (DC)	VI	Full	25	45	55	22	45	57	kΩ
Input Bandwidth (3 dB)	V	+25°C		100			100		MHz
Gain Flatness (to 15 MHz)	V	+25°C		0.25			0.25		dB
Integral Linearity	VI	Full	–1.0		+1.0	–1.0		+1.0	LSBs
Differential Linearity	VI	Full	–0.5		+0.5	–0.5		+0.5	LSBs
Monotonicity	VI	Full		Guaranteed			Guaranteed		
SWITCHING PERFORMANCE									
Max Conversion Rate	VI	Full	60			60			MSPS
Output Delay (t_V)[2]	IV	Full	4			4			ns
Output Delay (t_{PD})[2]	IV	Full			11			12	ns
Aperture Uncertainty (Jitter)	V	+25°C		10			10		ps rms
Aperture Time (t_A)	V	+25°C		1.0			1.0		ns
DYNAMIC PERFORMANCE[3]									
Effective Number of Bits	VI	+25°C	5.3	5.7		5.2	5.7		Bits
SINAD	VI	+25°C	34	36		33	36		dB
Harmonic Distortion (THD)	VI	+25°C	40	50		40	50		dB
Crosstalk Rejection	IV	+25°C	40	50		40	50		dBc
ENCODE INPUT									
Logic High Voltage	VI	Full	2.0			2.0			V
Logic Low Voltage	VI	Full			0.8			0.8	V
Input High Current	VI	Full			500			500	μA
Input Low Current	VI	Full			500			500	μA
Pulsewidth High	IV	Full	7.0			7.0			ns
Pulsewidth Low	IV	Full	7.0			7.0			ns
DIGITAL OUTPUTS									
Output Coding		Full		Offset Binary			Offset Binary		
Logic High Voltage (I_{OH} = 1 mA)	VI	Full	3.8			3.8			V
Logic Low Voltage (I_{OL} = 1 mA)	VI	Full			0.4			0.4	V
POWER SUPPLY									
$+V_S$ Supply Voltage	VI	Full	4.75		5.25	4.75		5.25	V
Power Supply Rejection Ratio[1]	IV	Full		110	130		110	130	mV/V
$+V_S$ Supply Current	VI	Full		80	120		80	120	mA
Power Dissipation[4]	VI	Full		400	600		400	600	mW

NOTES

[1]For ac coupled applications, the ADC is internally biased to insure that the midpoint transition of the ADC is within the limits specified with no signal applied. For dc coupled applications, the dc value of the midpoint transition voltage will track the supply voltage within the limits shown for dc input (midscale) plus the dc offset. Power Supply Rejection Ratio (PSRR) refers to the variation of the input signal range (gain) to supply voltage.

[2]t_V and t_{PD} are measured from the 1.4 V level of the Clock and the 50% level between V_{OH} and V_{OL}. The ac load on all the digital outputs during test is 10 pF (max), the dc load will not exceed ±40 μA.

[3]Effective number of bits (ENOB) and THD are measured using a FFT with a pure sine wave analog input @ 15.5 MHz, 1 dB below full scale. ENOB is calculated by ENOB = (SNR – 1.76 dB)/6.02; THD is measured from full scale to the sum of the second through seventh harmonic of the input.

[4]Typical thermal impedance for the "R" style (SOIC) 28-lead package is: θ_{JC} = 4°C/W, θ_{CA} = 41°C/W, θ_{JA} = 45°C/W, and the "RS" style (SSOP) 28-lead package is: θ_{JC} = 26.97°C/W, θ_{CA} = 51.61°C/W, θ_{JA} = 78.58°C/W.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

Pin	Min	Max	Unit
ENCODE	–0.5	$+V_S$	V
$+V_S$		7.0	V
INA, INB	–0.5	$+V_S$	V
VT	2.5	$+V_S$	V
REF A, REF B	–0.5	$+V_S$	V
VB	0.0	$+V_S$	V
D0–D5 Current OUT		20	mA

EXPLANATION OF TEST LEVELS

Test Level	Description
I	100% Production Tested
II	100% Production Tested at +25°C, and Sample Tested at Specified Temperatures
III	Sample Tested Only
IV	Parameter Is Guaranteed by Design
V	Parameter Is Typical Value Only
VI	100% Tested at +25°C

DIE LAYOUT AND MECHANICAL INFORMATION

Die Dimensions . . . . . 132 × 68 × 21 (±1) mils
Pad Dimensions . . . . . 4 × 4 mils
Metalization . . . . . Aluminum
Backing . . . . . None
Substrate Potential . . . . . Ground
Transistor Count 5,810
Passivation . . . . . Silicon Nitride
Die Attach . . . . . Silver Filled
Bond Wire . . . . . Gold

ORDERING GUIDE

Model	Temperature Range	Package Option*
AD9066AR	–40°C to +85°C	R-28
AD9066JR	0°C to +70°C	R-28
AD9066ARS	–40°C to +85°C	RS-28

*R = "SO" Small Outline Package; RS = SSOP.

PIN DESCRIPTIONS

AR:JR Pin No.	ARS Pin No.	Name	Function
1	22	ENCODE	TTL Compatible CMOS Clock, Samples on Rising Edge.
2	23	$+V_S$	+5 V Supply for Digital Input.
3	24	GND	Ground.
4	25	GND	Ground.
5	26	$+V_S$	+5 V Supply (Analog).
6	27	INA	Channel A Analog Input.
7	28	GND	Ground.
8	1	$+V_S$	+5 V Supply (Analog).
9	2	VT	Top of Voltage Reference, Bypass to GND.
10	3	REF A	Mid Reference to ADC A, Bypass to GND.
11	4	INB	Channel B Analog Input.
12	5	REF B	Mid Reference to ADC B, Bypass to GND.
13	6	VB	Bottom of Reference Ladder, Bypass to GND.
14	7	NC	No Connect.
15	8	D0B (LSB)	Digital Outputs Channel B, CMOS Compatible.
16	9	D1B	
17	10	D2B	
18	11	D3B	
19	12	D4B	
20	13	D5B (MSB)	
21	14	$+V_S$	+5 V Supply for Digital Outputs.
22	15	GND	Ground.
23	16	D0A (LSB)	Digital Outputs Channel A, CMOS Compatible.
24	17	D1A	
25	18	D2A	
26	19	D3A	
27	20	D4A	
28	21	D5A (MSB)	

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD9066 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

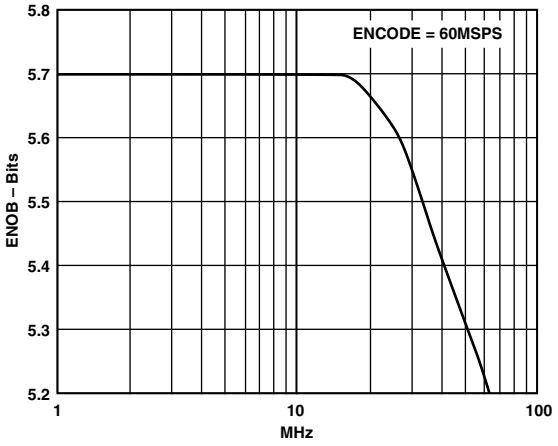


Figure 1. ENOB vs. Analog Input Frequency

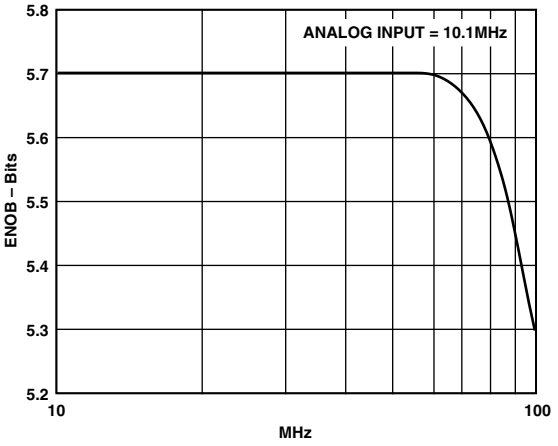


Figure 2. ENOB vs. Encode Rate

USING THE AD9066

Analog Input and Voltage References

The AD9066 is optimized to allow ac coupled inputs with a full-scale input range of 500 mV ± 5%. An LSB weight is approximately 8 mV. The full-scale input range is defined as the voltage range that accommodates $2^n - 2$ codes of equally weighted LSBs (between the first and last code transitions). For the AD9066 there are 32 codes above and below the midscale voltage of the A see Figure 3).

The full-scale input range of the AD9066 is equal to 500/620 × (VT – VB), or nominally 500 mV. For dc coupled applications, the REF A and REF B voltages can be used to feed back offset compensation signals. This will allow the midscale transition voltage of the ADCs to track supply and temperature variations.

In the event that offset correction signals are generated digitally, the REF pins would not be required. Figure 4a shows the equivalent circuit for the internal references. All component tolerances are ±25%.

Gain Variation

The full-scale input range is established by the current through the two matched resistor ladders (620 ohms each nominal). Therefore the gain of the ADC may be modified by forcing different voltages across the top and bottom voltage taps (VT and VB).

The easiest way to increase the input range will be to force VB to a lower voltage. Using an external amplifier, the voltage at VB may be forced as low as 3.0 V (3.58 nominal). Using the previously described relationship for full scale and the internal resistor ladder values, 3.0 V at VB will result in a nominal full-scale input range of 705 mV.

A larger input range can be established by taking the VT voltage all the way to the supply voltage level while pulling VB to 3.0 V. This would force a 2 V potential across the ladder and create a full-scale input range of 1.6 V.

Greater flexibility and improved power supply rejection can be achieved by forcing external voltage references at both the top and bottom of the resistor ladder.

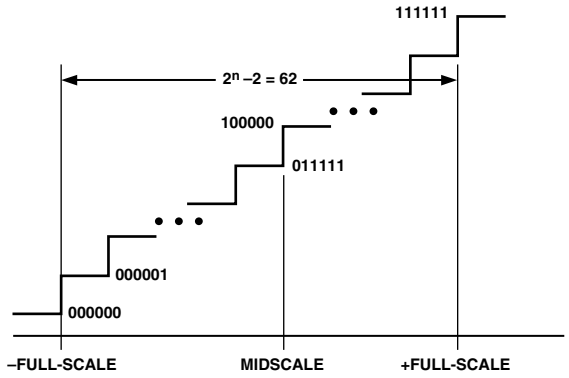
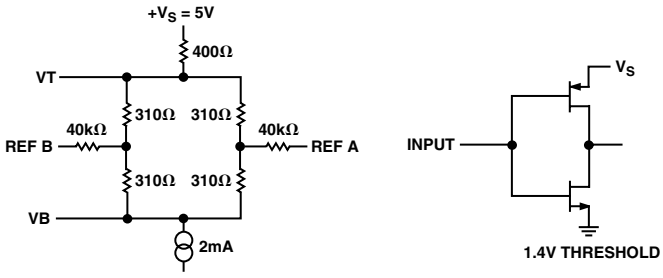


Figure 3.



a. Reference Circuit *b. Encode Input*

c. Output Bits *d. Analog Input*

Figure 4. Equivalent Circuits

Timing

The duty cycle of the encode clock for the AD9066 is critical in obtaining rated performance of the ADC. Rated maximum and minimum pulse widths should be maintained, especially for sample rates greater than 40 MSPS.

The AD9066 provides latched data outputs with three pipeline delays. The length and load on the output data lines should be minimized to reduce power supply transients inside the AD9066 which might diminish dynamic performance.

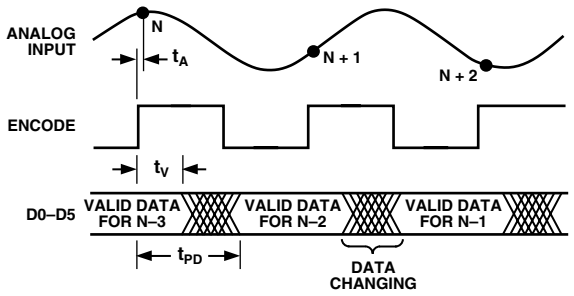


Figure 5. Timing Diagram

The data is invalid during the period between t_V and t_{PD}. This period refers to the time required for the AD9066 to fully switch between valid CMOS logic levels. When latching the output data, be careful to observe latch setup and hold time restrictions as well as this data invalid period when designing the system timing.

Layout and Signal Care

To insure optimum performance, a single low impedance ground plane is recommended. Analog and digital grounds should be connected together at the AD9066. Analog and digital power supplies should be bypassed, at the device, to ground through 0.1 μF ceramic capacitors.

The use of sockets may limit the dynamic performance of the part and is not recommended except for prototype or evaluation purposes.

Driving the AD9066 with a Bipolar Input

The analog input range of the AD9066 is between 3.7 V and 4.2 V. Because the input is offset, the normal method of driving the analog input is to use a blocking capacitor between the analog source and the AD9066 analog input pins. In applications where DC coupling must be employed, the simple circuit shown in Figure 6 will take a bipolar input and offset it to the operating range of the AD9066.

To offset the input, the midpoint voltage of the AD9066 is buffered off chip and then inverted with an AD712, a low input bias current dual op amp. This inverted midpoint is then fed to a summation amplifier that combines the bipolar input with the inverted offset voltage. The summation amplifier is an AD812, a wideband current feedback amplifier that provides good bandwidth and low distortion.

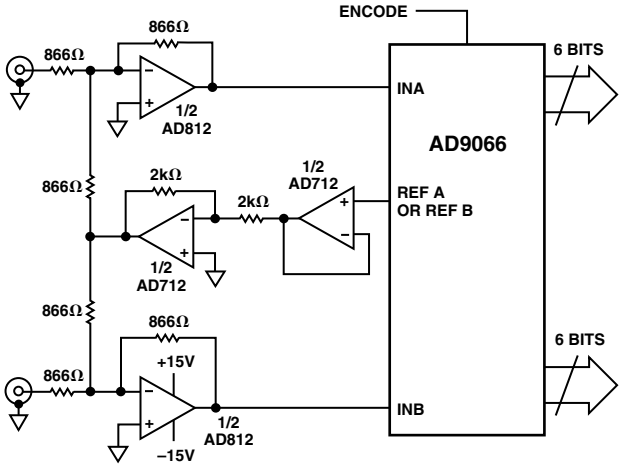


Figure 6. Bipolar Input Using AD812 Drive for AD9066

Layout should follow high frequency/high speed design guidelines. In addition the capacitance around the inverting input to the AD812 should be minimized through a tight layout and the use of low capacitance chip resistors for gain setting.

Quadrature Receiver Using the AD9066

Although any type of input signal may be applied, the AD9066 has been optimized for low cost in-phase and quadrature (I and Q) demodulators. Primary applications include digital direct broadcast satellite applications where broadband quadrature phase shift keying (QPSK) modulation is used. In these receivers the recovered signal is separated into I and Q vector components and digitized.

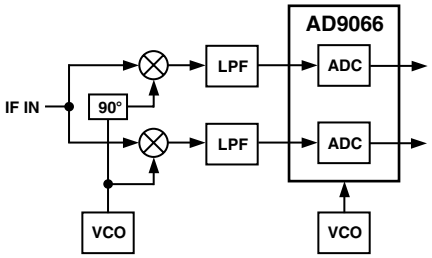


Figure 7. Simplified Block Diagram

For data symbol rates less than 10 Mbaud, the AD607 IF/RF receiver subsystem provides an ideal solution for the second conversion stage of a complete receiver system. Figure 8 shows the AD9066 and AD607 used together.

The AD607 accepts inputs as high as 500 MHz which may be the output of the first IF stage or RF signals directly. The IF/RF signal is mixed with the local oscillator to provide an IF frequency of 400 kHz to 22 MHz. This signal is filtered externally and then amplified with an on-chip AGC before being synchronously demodulated with an on-chip PLL carrier recovery circuit. The outputs are digitized with the AD9066. The digital outputs may be processed with a DSP chip such as the ADSP-2171, ADSP-21062, general purpose DSP or ASIC.

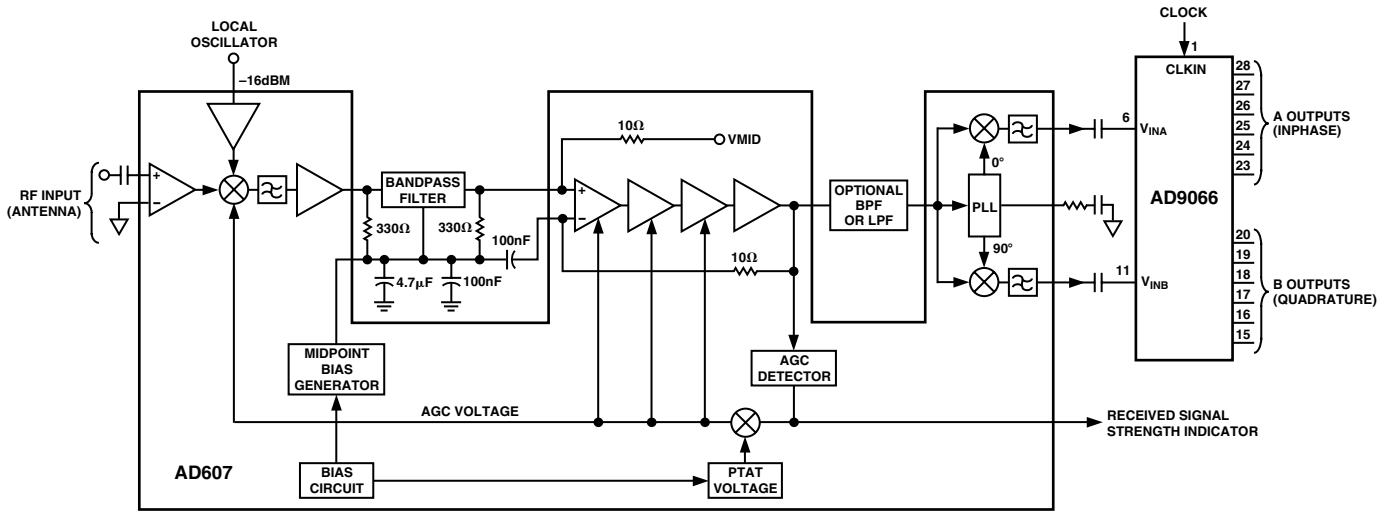


Figure 8. Digitizer with AD607 Receiver Circuit

Theory of Operation

The AD9066 dual ADC employs a patented interpolated flash architecture. This architecture enables 64 possible quantization levels with only 32 comparator preamplifiers. This keeps input capacitance to a minimum. The midpoint of the reference ladder is fed back to the analog input, allowing easy biasing of the ADC to midscale for ac coupled applications.

As shown in Figure 4d, a simple resistor is used to provide the reference ladder midpoint to the analog input. The high impedance MOS inputs of the comparators insure no static voltage drop across the resistor. This eliminates the need for an active buffer (and its inherent offsets) to set the reference midpoint at the analog input.

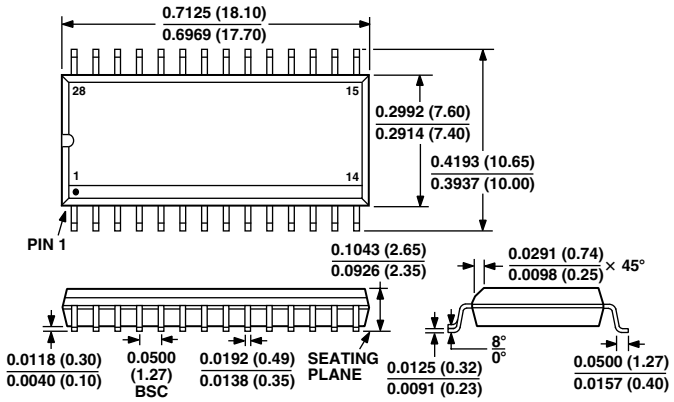
The outputs of the comparators are converted to a 6-bit word and converted to CMOS levels. The digital signals are latched at six stages (two pipeline delays) in the signal path. The digital outputs are CMOS with approximately equal rise and fall times.

The encode clock utilizes a CMOS input stage with TTL-compatible (1.4 V) thresholds. Internal clock buffers minimize external clock drive requirements.

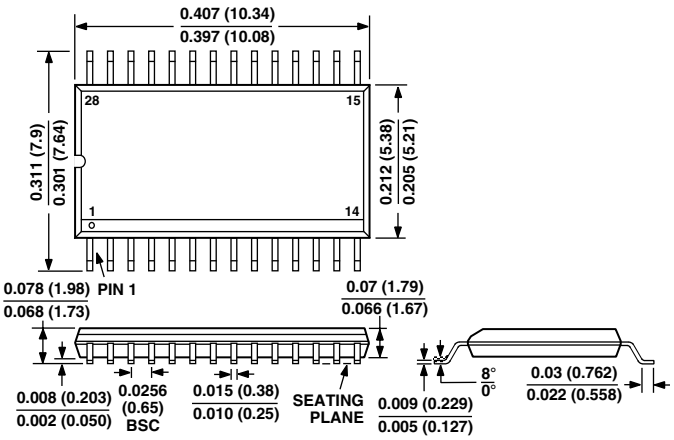
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

28-Lead Small Outline Package
(R-28)



28-Lead SSOP
(RS-28)



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